2SD2530

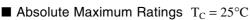
Silicon NPN triple diffusion planar type Darlington

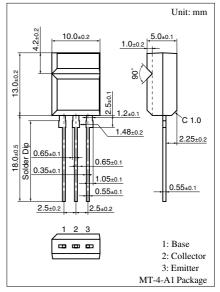
For power amplification

Features

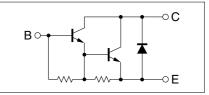
- \bullet High forward current transfer ratio h_{FE}
- Allowing supply with the radial taping
- Low collector to emitter saturation voltage $V_{CE(sat)}$: < 2.5 V

| Absolute Maximum Ratings $T_c = 23 C$ | | | | | | | | |
|---------------------------------------|---------------------|------------------|-------------|------|--|--|--|--|
| Parameter | | Symbol | Rating | Unit | | | | |
| Collector to base voltage | | V _{CBO} | 100 | V | | | | |
| Collector to emitter voltage | | V _{CEO} | 100 | V | | | | |
| Emitter to base voltage | | V _{EBO} | 5 | V | | | | |
| Peak collector current | | I _{CP} | 10 | А | | | | |
| Collector current | | I _C | 5 | А | | | | |
| Collector power | $T_C = 25^{\circ}C$ | P _C | 15 | W | | | | |
| dissipation | $T_a = 25^{\circ}C$ | | 2 | | | | | |
| Junction temperature | | Tj | 150 | °C | | | | |
| Storage temperature | | T _{stg} | -55 to +150 | °C | | | | |





Internal Connection



\blacksquare Electrical Characteristics $T_C = 25^{\circ}C \pm 2^{\circ}C$

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|---|----------------------|---|-------|------|--------|------|
| Collector cutoff current | I _{CBO} | $V_{CB} = 100 \text{ V}, I_E = 0$ | | | 100 | μΑ |
| | I _{CEO} | $V_{CE} = 80 \text{ V}, I_B = 0$ | | | 100 | μΑ |
| Emitter cutoff current | I_{EBO} | $V_{EB} = 5 V, I_C = 0$ | | | 5 | mA |
| Collector to emitter voltage | V _{CEO} | $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$ | 100 | | | V |
| Forward current transfer ratio | h _{FE1} | $V_{CE} = 4 V, I_C = 2 A$ | 2 000 | | 15 000 | |
| | h _{FE2} | $V_{CE} = 4 V, I_C = 4 A$ | 500 | | | |
| Collector to emitter saturation voltage | V _{CE(sat)} | $I_{\rm C} = 2 \text{ A}, I_{\rm B} = 2 \text{ mA}$ | | | 1.5 | V |
| | | $I_{\rm C} = 4 \text{ A}, I_{\rm B} = 16 \text{ mA}$ | | | 2.5 | V |
| Base to emitter saturation voltage | V _{BE(sat)} | $I_{\rm C} = 4 \text{ A}, I_{\rm B} = 16 \text{ mA}$ | | | 2.5 | V |
| Transition frequency | f_T | $V_{CE} = 10 \text{ V}, I_C = 0.5 \text{ A}, f = 1 \text{ MHz}$ | | 20 | | MHz |
| Turn-on time | t _{on} | $I_{C} = 4 \text{ A}, I_{B1} = 16 \text{ mA}, I_{B2} = -16 \text{ mA},$ | | 0.27 | | μs |
| Storage time | t _{stg} | $V_{CC} = 50 V$ | | 2.9 | | μs |
| Fall time | t _f | 1 | | 1.0 | | μs |

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